

TC74LVX273F, TC74LVX273FW, TC74LVX273FT**OCTAL D-TYPE FLIP FLOP WITH CLEAR**

The TC74LVX273 is a high speed CMOS OCTAL D-FLIP FLOP fabricated with silicon gate C²MOS technology. Designed for use in 3.3 Volt systems, it achieves high speed operation while maintaining the CMOS low power dissipation.

This device is suitable for low voltage and battery operated systems.

Information signals applied to D inputs are transferred to the Q outputs on the positive going edge of the clock pulse.

When the $\overline{\text{CLR}}$ input is held low, the Q outputs are in the low logic level independent of the other inputs.

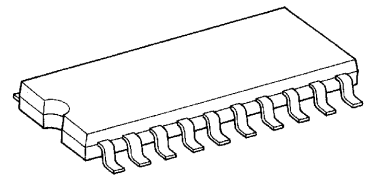
An input protection circuit ensures that 0 to 7V can be applied to the input pins without regard to the supply voltage. This device can be used to interface 5V to 3V systems and two supply systems such as battery back up. This circuit prevents device destruction due to mismatched supply and input voltages.

FEATURES

- High speed : $f_{\text{MAX}} = 150\text{MHz}$ (Typ.) ($V_{\text{CC}} = 3\text{V}$)
- Low power dissipation : $I_{\text{CC}} = 4\mu\text{A}$ (Max.) ($T_a = 25^\circ\text{C}$)
- Input voltage level : $V_{\text{IL}} = 0.8\text{V}$ (Max.) ($V_{\text{CC}} = 3\text{V}$)
 $V_{\text{IH}} = 2.0\text{V}$ (Min.) ($V_{\text{CC}} = 3\text{V}$)
- Power down protection is provided on all inputs.
- Balanced propagation delays : $t_{\text{pLH}} \approx t_{\text{pHL}}$
- Low noise : $V_{\text{OLP}} = 0.8\text{V}$ (Max.)
- Pin and function compatible with 74HC273

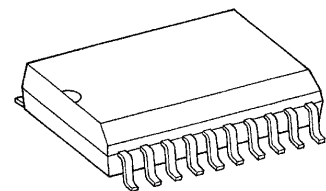
(Note) The JEDEC SOP (FW) is not available in Japan.

TC74LVX273F



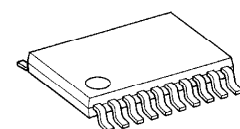
SOP20-P-300-1.27

TC74LVX273FW



SOL20-P-300-1.27

TC74LVX273FT

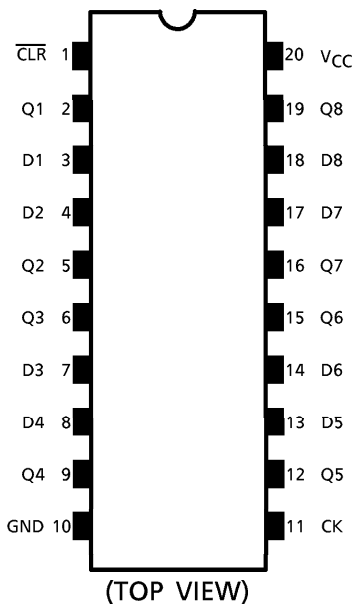


TSSOP20-P-0044-0.65

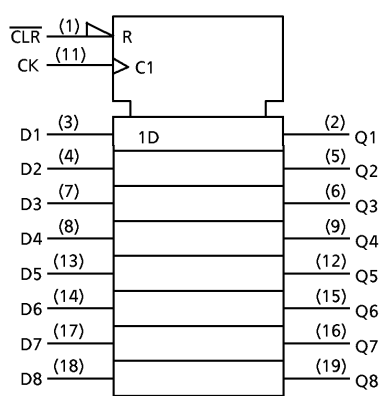
Weight

SOP20-P-300-1.27	: 0.22g (Typ.)
SOL20-P-300-1.27	: 0.46g (Typ.)
TSSOP20-P-0044-0.65	: 0.08g (Typ.)

PIN ASSIGNMENT



IEC LOGIC SYMBOL

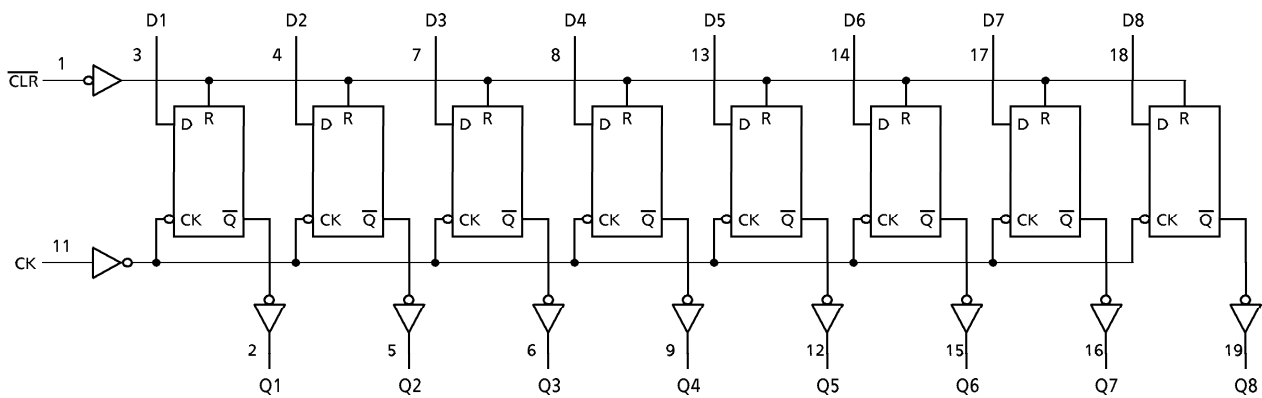


TRUTH TABLE

INPUTS			OUTPUTS	FUNCTION
CLR	D	CK	Q	
L	X	X	L	CLEAR
H	L		L	—
H	H		H	—
H	X		Qn	NO CHANGE

X : Don't Care

SYSTEM DIAGRAM



MAXIMUM RATINGS

PARAMETER	SYMBOL	RATING	UNIT
Supply Voltage Range	V_{CC}	-0.5~7.0	V
DC Input Voltage	V_{IN}	-0.5~7.0	V
DC Output Voltage	V_{OUT}	-0.5~ V_{CC} +0.5	V
Input Diode Current	I_{IK}	-20	mA
Output Diode Current	I_{OK}	±20	mA
DC Output Current	I_{OUT}	±25	mA
DC V_{CC} / Ground Current	I_{CC}	±75	mA
Power Dissipation	P_D	180	mW
Storage Temperature	T_{stg}	-65~150	°C

RECOMMENDED OPERATING CONDITIONS

PARAMETER	SYMBOL	RATING	UNIT
Supply Voltage	V_{CC}	2.0~3.6	V
Input Voltage	V_{IN}	0~5.5	V
Output Voltage	V_{OUT}	0~ V_{CC}	V
Operating Temperature	T_{opr}	-40~85	°C
Input Rise And Fall Time	dt/dv	0~100	ns/V

ELECTRICAL CHARACTERISTICS

DC characteristics

PARAMETER		SYM-BOL	TEST CONDITION		V _{CC} (V)	Ta = 25°C			Ta = - 40~85°C		UNIT
						MIN.	TYP.	MAX.	MIN.	MAX.	
Input Voltage	"H" Level	V _{IH}			2.0	1.5	—	—	1.5	—	V
					3.0	2.0	—	—	2.0	—	
					3.6	2.4	—	—	2.4	—	
	"L" Level	V _{IL}			2.0	—	—	0.5	—	0.5	
					3.0	—	—	0.8	—	0.8	
					3.6	—	—	0.8	—	0.8	
Output Voltage	"H" Level	V _{OH}	V _{IN} = V _{IH}	I _{OH} = - 50μA	2.0	1.9	2.0	—	1.9	—	V
			or V _{IL}	I _{OH} = - 50μA	3.0	2.9	3.0	—	2.9	—	
				I _{OH} = - 4mA	3.0	2.58	—	—	2.48	—	
	"L" Level	V _{OL}	V _{IN} = V _{IH}	I _{OL} = 50μA	2.0	—	0.0	0.1	—	0.1	
			or V _{IL}	I _{OL} = 50μA	3.0	—	0.0	0.1	—	0.1	
				I _{OL} = 4mA	3.0	—	—	0.36	—	0.44	
			Input Leakage Current		I _{IN}	V _{IN} = 5.5V or GND		3.6	—	—	
Quiescent Supply Current		I _{CC}	V _{IN} = V _{CC} or GND		3.6	—	—	4.0	—	40.0	μA

Timing requirements (Input $t_r = t_f = 3\text{ns}$)

PARAMETER	SYM-BOL	TEST CONDITION	Ta = 25°C		Ta = -40~85°C	UNIT
			V _{CC} (V)	LIMIT		
Minimum Pulse Width (CK)	t _W (L)		2.7	8.0	9.5	ns
	t _W (H)		3.3 ± 0.3	5.5	6.5	
Minimum Pulse Width (CLR)	t _W (L)		2.7	7.5	8.5	ns
			3.3 ± 0.3	5.0	6.0	
Minimum Set-up Time	t _s		2.7	8.0	9.5	ns
			3.3 ± 0.3	5.5	6.5	
Minimum Hold Time	t _h		2.7	1.0	1.0	ns
			3.3 ± 0.3	1.0	1.0	
Minimum Removal Time (CLR)	t _{rem}		2.7	4.0	4.0	ns
			3.3 ± 0.3	2.5	2.5	

AC characteristics (Input $t_r = t_f = 3\text{ns}$)

PARAMETER	SYM-BOL	TEST CONDITION			Ta = 25°C			Ta = - 40~85°C		UNIT
			V _{CC} (V)	C _L (pF)	MIN.	TYP.	MAX.	MIN.	MAX.	
Propagation Delay Time (CK-Q)	t _{pLH}		2.7	15	—	9.0	16.9	1.0	20.5	ns
	50			—	11.5	20.4	1.0	24.0		
	t _{pHL}		3.3 ± 0.3	15	—	7.1	11.0	1.0	13.0	
				50	—	9.6	14.5	1.0	16.5	
Propagation Delay Time (CLR-Q)	t _{pHL}		2.7	15	—	9.3	17.6	1.0	20.5	ns
				50	—	11.8	21.1	1.0	24.0	
			3.3 ± 0.3	15	—	7.3	11.5	1.0	13.5	
				50	—	9.8	15.0	1.0	17.0	
Maximum Clock Frequency	f _{MAX}		2.7	15	55	110	—	55	—	MHz
				50	45	60	—	40	—	
			3.3 ± 0.3	15	95	150	—	80	—	
				50	60	90	—	50	—	
Output To Output Skew	t _{osLH}	(Note 1)	2.7	50	—	—	1.5	—	1.5	ns
	t _{osHL}		3.3 ± 0.3	50	—	—	1.5	—	1.5	
Input Capacitance	C _{IN}	(Note 2)			—	4	10	—	10	pF
Power Dissipation Capacitance	C _{PD}	(Note 3)			—	31	—	—	—	pF

(Note 1) Parameter guaranteed by design.

(t_{osLH} = |t_{pLHm} - t_{pLHn}|, t_{osHL} = |t_{pHLm} - t_{pHLn}|)

(Note 2) Parameter guaranteed by design.

(Note 3) C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption.

Average operating current can be obtained by the equation :

$$I_{CC}(\text{opr.}) = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/8 \text{ (per F/F)}$$

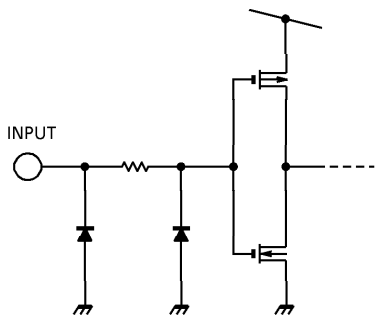
And the total CPD when n pcs. of F/F operate can be gained by the following equation :

$$C_{PD}(\text{total}) = 22 + 9 \cdot n$$

Noise characteristics (Ta = 25°C, Input tr = tf = 3ns, CL = 50pF)

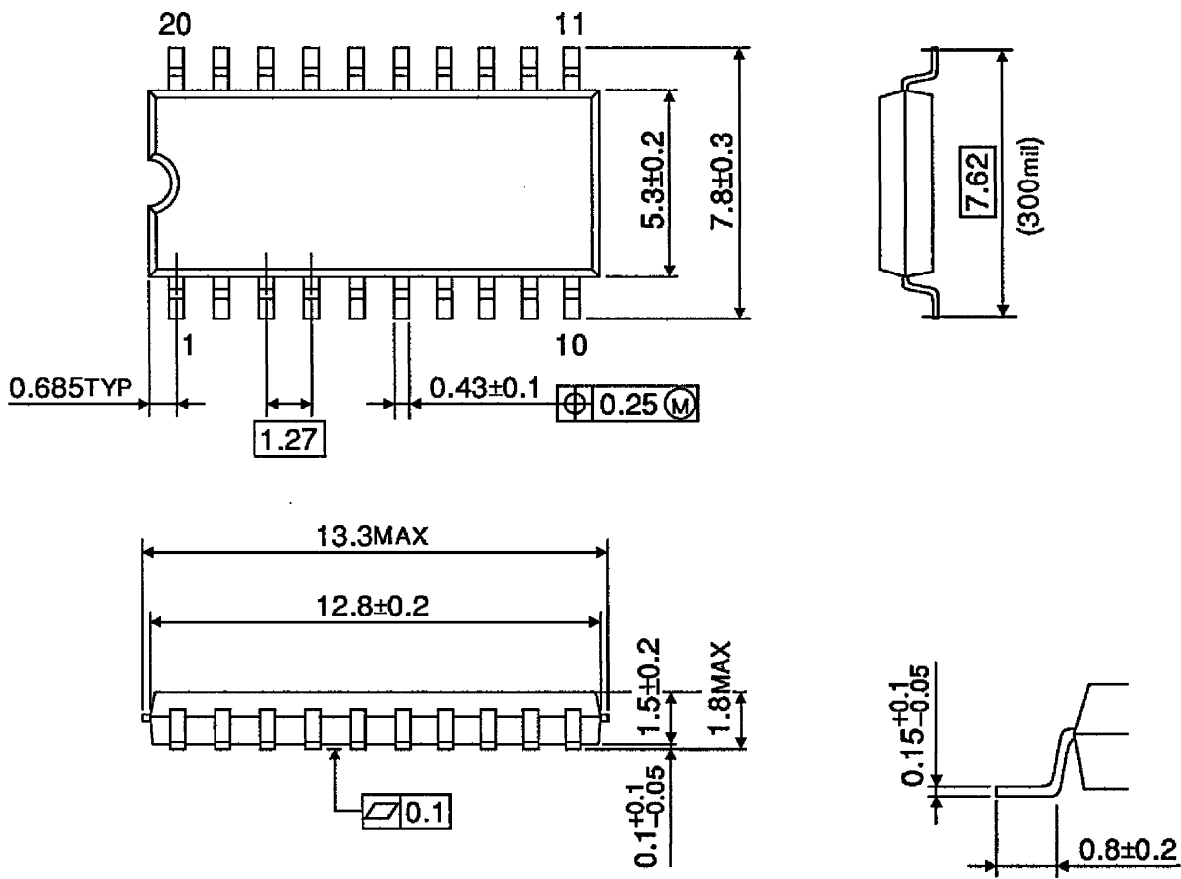
PARAMETER	SYMBOL	TEST CONDITION	VCC (V)	TYP.	LIMIT	UNIT
Quiet Output Maximum Dynamic VOL	VOLP		3.3	0.5	0.8	V
Quiet Output Minimum Dynamic VOL	VOLV		3.3	-0.5	-0.8	V
Minimum High Level Dynamic Input Voltage	VIHD		3.3	—	2.0	V
Maximum Low Level Dynamic Input Voltage	VILD		3.3	—	0.8	V

INPUT EQUIVALENT CIRCUIT



PACKAGE DIMENSIONS
SOP20-P-300-1.27

Unit : mm



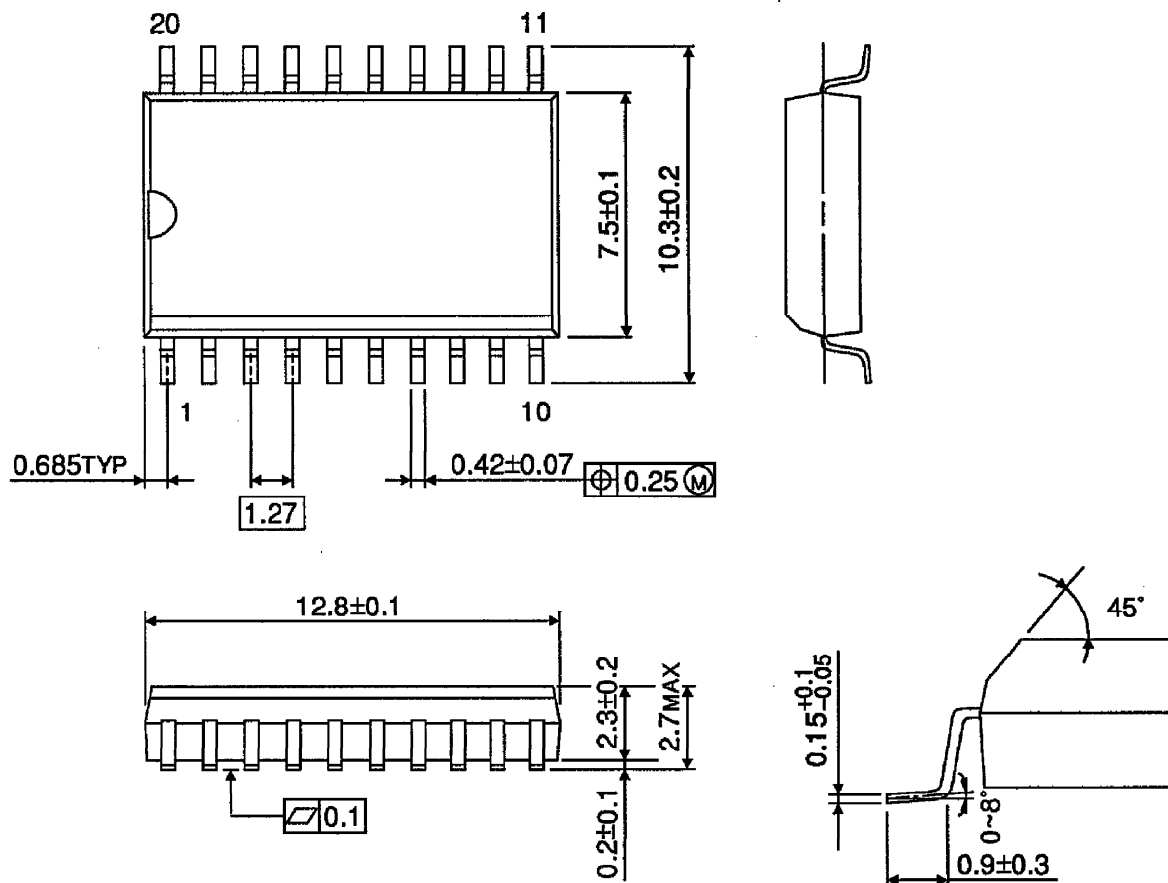
Weight : 0.22g (Typ.)

PACKAGE DIMENSIONS

SOL20-P-300-1.27

Unit : mm

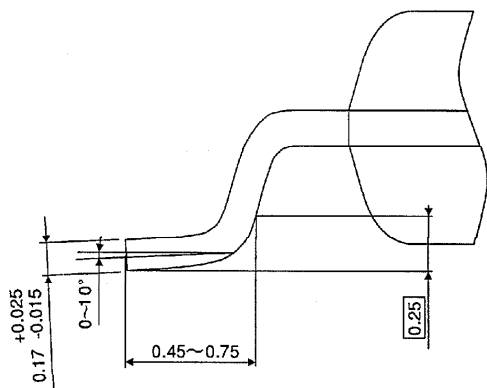
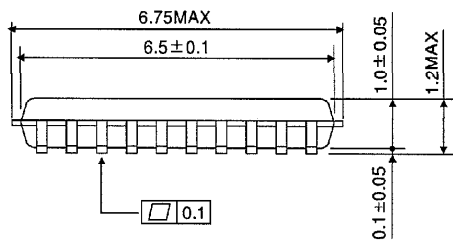
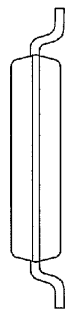
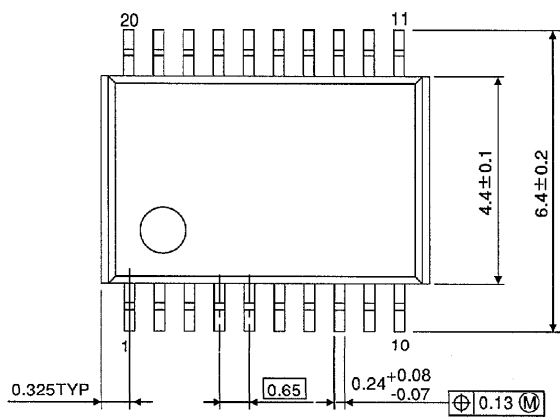
(Note) This package is not available in Japan.



Weight : 0.46g (Typ.)

PACKAGE DIMENSIONS
TSSOP20-P-0044-0.65

Unit : mm



Weight : 0.08g (Typ.)

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000707EBA

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